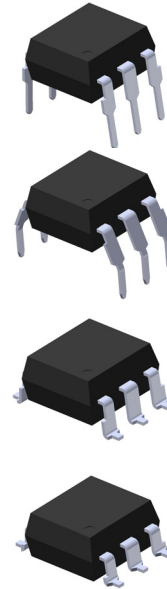


6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

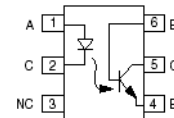
CNY17-X Series CNY17F-X Series

Features

- Current transfer ratios in selected narrow range groups
 CNY17-1, CNY17F-1: 40-80%
 CNY17-2, CNY17F-2: 63-125%
 CNY17-3, CNY17F-3: 100-200%
 CNY17-4, CNY17F-4: 160-320%
- High isolation voltage between input and output
 (Viso = 5000 Vrms)
- Creepage distance > 7.6 mm
- Operating temperature up to +110°C
- The CNY17F-X series offers no external base connection
 for minimum noise susceptibility
- Compact dual-in-line package
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CSA approved

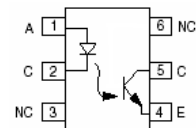


Schematic



CNY17-X

1. Anode
2. Cathode
3. No Connection
4. Emitter
5. Collector
6. Base



CNY17F-X

1. Anode
2. Cathode
3. No Connection
4. Emitter
5. Collector
6. No Connection

Description

The CNY17-X and CNY17F-X series of devices each consist of an infrared emitting diode optically coupled to a phototransistor.

It is packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs



LIGHTING FOREVER

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Absolute Maximum Ratings ($T_a=25^{\circ}\text{C}$)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	60	mA
	Peak forward current ($t = 10\mu\text{s}$)	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation ($T_A = 25^{\circ}\text{C}$)	P_D	100	mW
	Derating factor (above 100°C)		3.8	mW/ $^{\circ}\text{C}$
Output	Collector-Emitter voltage	V_{CEO}	80	V
	Collector-Base voltage ^{*1}	V_{CBO}	80	V
	Collector current	I_C	50	mA
	Emitter-Collector voltage	V_{ECO}	7	V
	Power dissipation ($T_A = 25^{\circ}\text{C}$)	P_C	150	mW
Derating factor (above 100°C)	9.0		mW/ $^{\circ}\text{C}$	
Total power dissipation		P_{tot}	200	mW
Isolation voltage ^{*2}		V_{iso}	5000	Vrms
Operating temperature		T_{opr}	-55~+110	$^{\circ}\text{C}$
Storage temperature		T_{stg}	-55~+125	$^{\circ}\text{C}$
Soldering temperature ^{*3}		T_{sol}	260	$^{\circ}\text{C}$

Notes

*1 Only for CNY17-X series.

*2 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

*3 For 10 seconds.



LIGHTING FOREVER

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Electrical Characteristics ($T_a=25^\circ\text{C}$ unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward voltage	V_F	-	-	1.65	V	$I_F = 60\text{mA}$
Reverse current	I_R	-	-	10	μA	$V_R = 6\text{V}$
Input capacitance	C_{in}	-	18	-	pF	$V = 0, f = 1\text{MHz}$

Output

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Base dark current	CNY17-X only I_{CBO}	-	-	20	nA	$V_{CB} = 10\text{V}, I_F = 0\text{mA}$
Collector-Emitter dark current	I_{CEO}	-	-	50	nA	$V_{CE} = 10\text{V}, I_F = 0\text{mA}$
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	$I_C = 1\text{mA}, I_F = 0\text{mA}$
Collector-Base breakdown voltage	CNY17-X only BV_{CBO}	80	-	-	V	$I_C = 0.1\text{mA}, I_F = 0\text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	7	-	-	V	$I_E = 0.1\text{mA}, I_F = 0\text{mA}$
Collector-Emitter capacitance	C_{CE}	-	8	-	pF	$V_{CE} = 0\text{V}, f = 1\text{MHz}$

* Typical values at $T_a = 25^\circ\text{C}$



LIGHTING FOREVER

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Transfer Characteristics ($T_a=25^\circ\text{C}$ unless specified otherwise)

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition
Current Transfer Ratio	CNY17-1 CNY17F-1	CTR	40	-	80	%	$I_F = 10\text{mA}, V_{CE} = 5\text{V}$
	CNY17-2 CNY17F-2		63	-	125		
	CNY17-3 CNY17F-3		100	-	200		
	CNY17-4 CNY17F-4		160	-	320		
Current Transfer Ratio	CNY17-1 CNY17F-1	CTR	13	-	-	%	$I_F = 1\text{mA}, V_{CE} = 5\text{V}$
	CNY17-2 CNY17F-2		22	-	-		
	CNY17-3 CNY17F-3		34	-	-		
	CNY17-4 CNY17F-4		56	-	-		
Collector-Emitter saturation voltage		$V_{CE(sat)}$	-	-	0.3	V	$I_F = 10\text{mA}, I_C = 2.5\text{mA}$
Isolation resistance		R_{IO}	10^{11}	-	-	Ω	$V_{IO} = 500\text{Vdc}$
Input-output capacitance		C_{IO}	-	0.5	-	pF	$V_{IO} = 0, f = 1\text{MHz}$
Turn-on time		T_{on}	-	10	12	μs	$V_{CC} = 10\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$ See Fig. 11
Turn-off time		T_{off}	-	9	12		
Rise time		T_r	-	6	10		
Fall time		T_f	-	8	10		
Rise time		T_r	-	2	10		$V_{CC} = 5\text{V}, I_F = 10\text{mA}, R_L = 75\Omega$, See Fig. 11
Fall time		T_f	-	3	10		

* Typical values at $T_a = 25^\circ\text{C}$

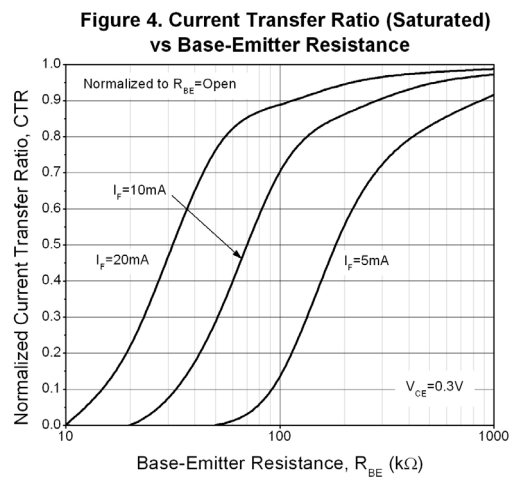
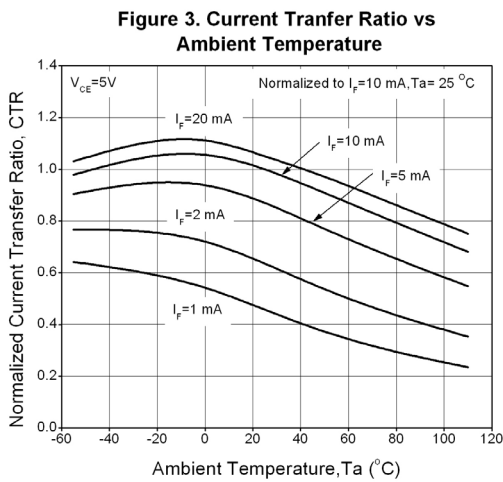
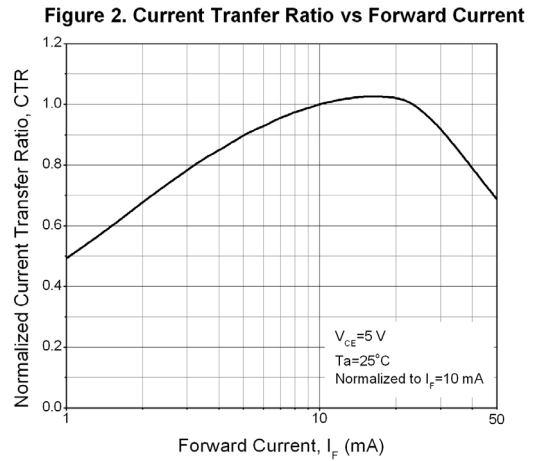


LIGHTING FOREVER

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Typical Performance Curves



6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Figure 7. Collector-Emitter Saturation Voltage vs Collector Current

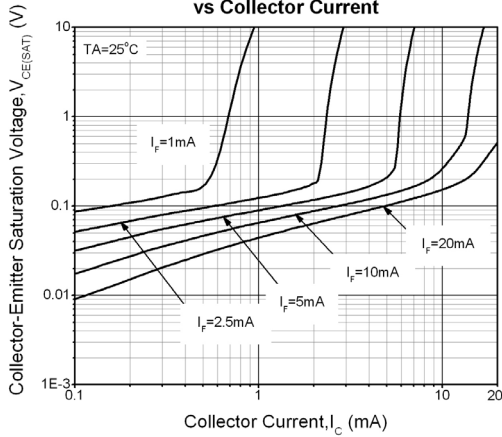


Figure 8. Switching Time vs Load Resistance

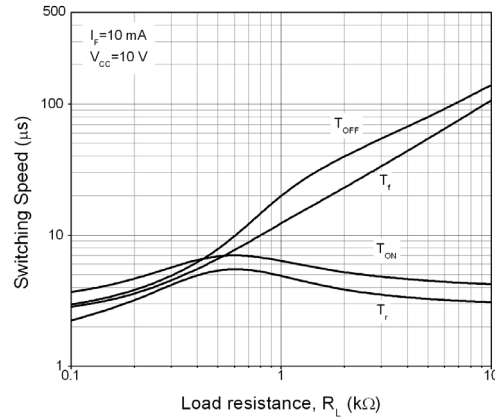


Figure 9. Turn-on Time vs Base-Emitter Resistance

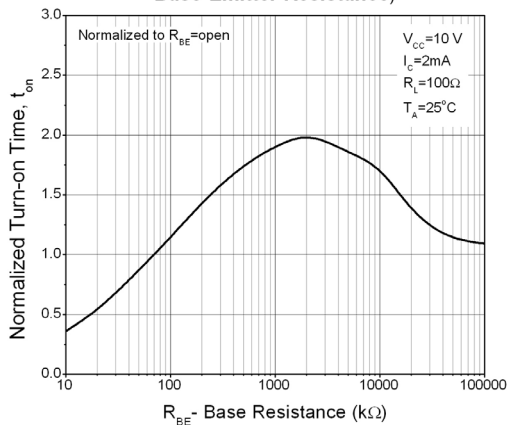


Figure 10. Turn-off Time vs Base-Emitter Resistance

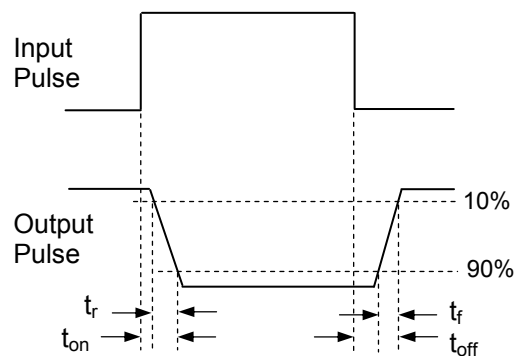
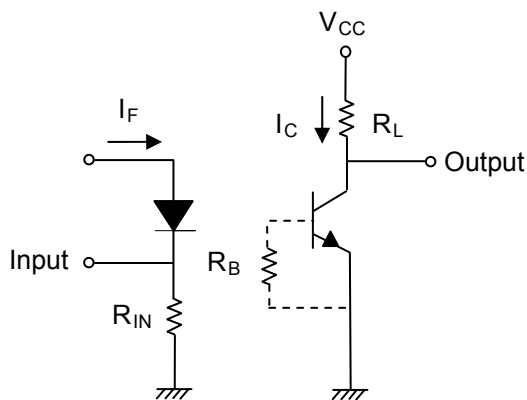


Figure 11. Switching Time Test Circuit & Waveforms



LIGHTING FOREVER

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series
CNY17F-X Series

Order Information

Part Number

CNY17-XY(Z)-V

or

CNY17F-XY(Z)-V

Note

- X = Part no. (1, 2, 3 or 4)
- Y = Lead form option (S, S1, M or none)
- Z = Tape and reel option (TA, TB or none).
- V = VDE (optional)

Option	Description	Packing quantity
None	Standard DIP-6	65 units per tube
M	Wide lead bend (0.4 inch spacing)	65 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel



LIGHTING FOREVER

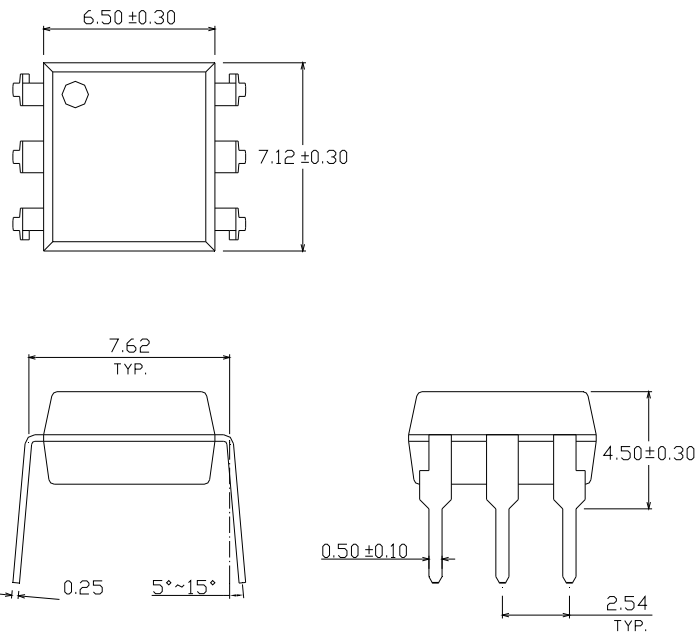
6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Package Drawings

(Dimensions in mm)

Standard DIP Type



Option M Type





LIGHTING FOREVER

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Option S Type



Option S1 Type





LIGHTING FOREVER

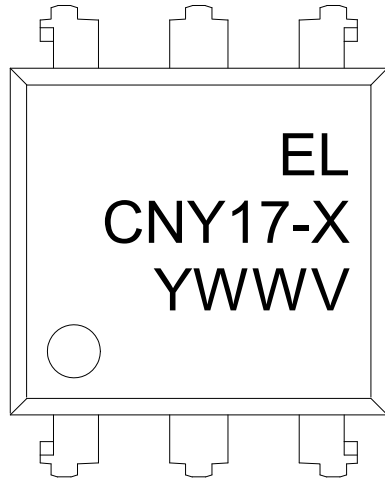
6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Recommended pad layout for surface mount leadform



Device Marking



Notes

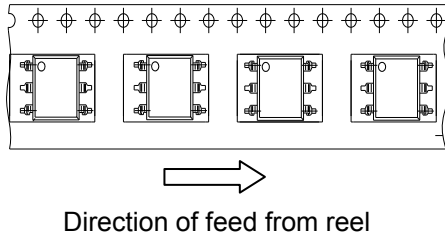
- EL denotes Everlight
- CNY17-X denotes Device Number (X: 1, 2, 3 or 4)
- Y denotes 1 digit Year code
- WW denotes 2 digit Week code
- V denotes VDE (optional)

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

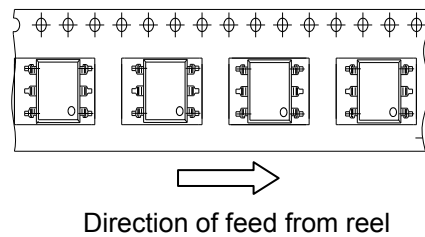
CNY17-X Series CNY17F-X Series

Tape & Reel Packing Specifications

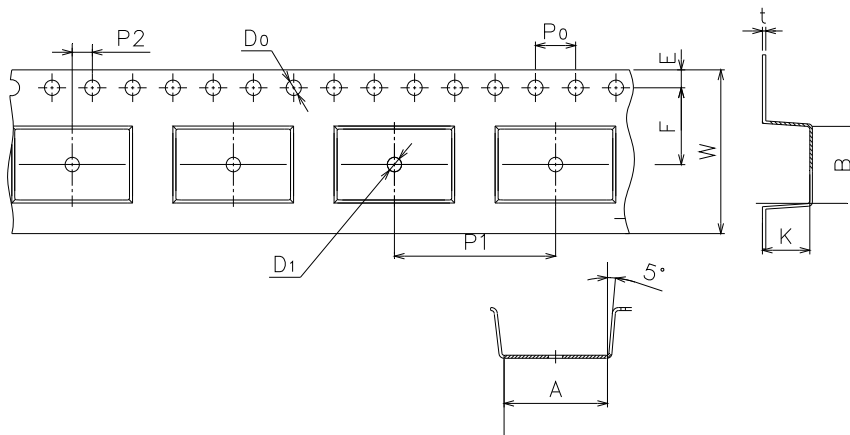
Option TA



Option TB



Tape dimensions



Dimension No.	A	B	Do	D1	E	F
Dimension (mm)	10.4±0.1	7.52±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1

Dimension No.	Po	P1	P2	t	W	K
Dimension (mm)	4.0±0.15	16.0±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1

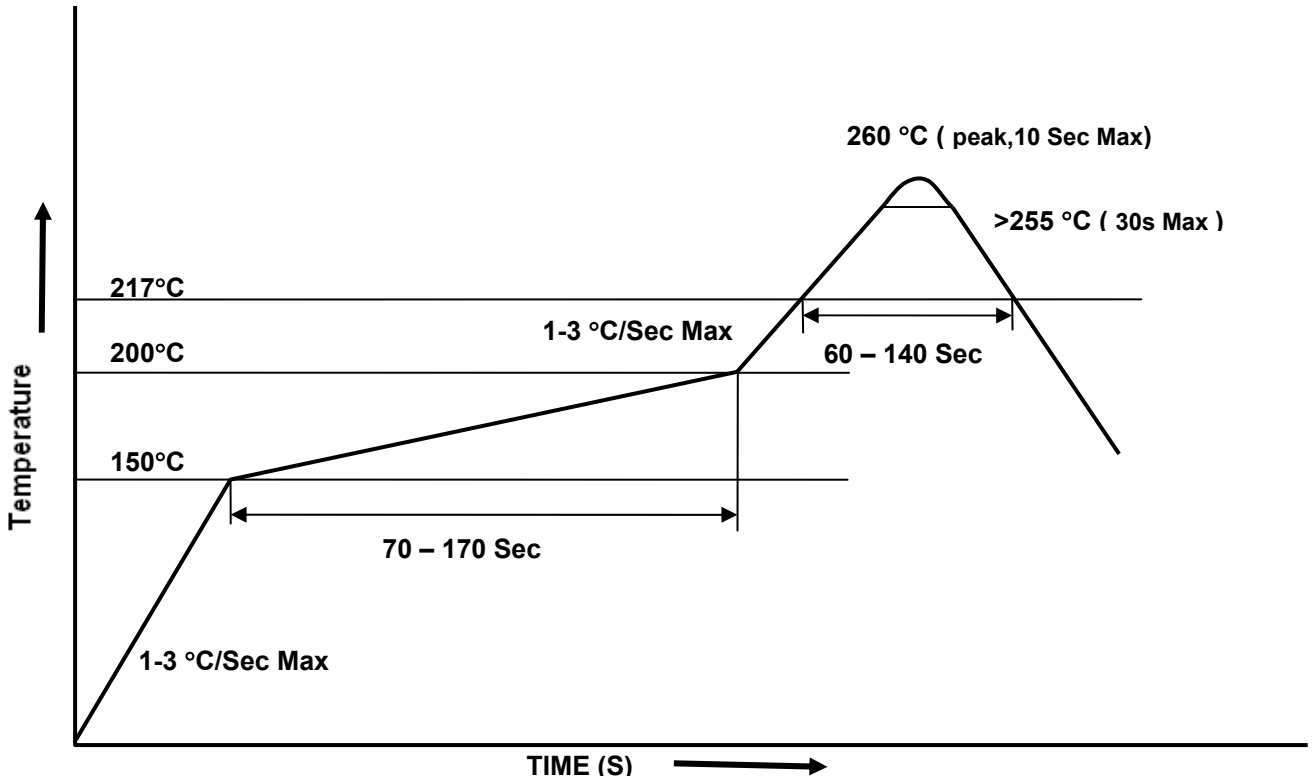


LIGHTING FOREVER

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Solder Reflow Temperature Profile





LIGHTING FOREVER

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series
CNY17F-X Series

DISCLAIMER

1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
3. These specification sheets include materials protected under copyright of EVERLIGHT. Reproduction in any form is prohibited without the specific consent of EVERLIGHT.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9